NSN 5961-01-263-6437

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-263-6437 **Inclosure Material:** Metal **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 8.0 collector to emitter saturation voltage **Current Rating Per Characteristic:** 10.00 milliamperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 353.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 25.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli